NSN 5962-00-530-4663

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View Online at https://aerobasegroup.com/nsn/5962-00-530-4663

Body Length:
Between 0.370 inches and 0.395 inches
Body Width:
Between 0.245 inches and 0.275 inches
Body Height:
Between 0.050 inches and 0.080 inches
Maximum Power Dissipation Rating:
580.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+200.0 degrees celsius
Features Provided:
Monolithic and hermetically sealed and negative edge triggered and positive outputs
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
Dual 6 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
40.00 nanoseconds propagation delay time, low to high level output and 45.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Special Features:
Formed leads
Precious Material And Location:
Terminal surface gold
Precious Material:

Gold Test Data Document:

94117-310131 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

24 flat leads

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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